



#### PNP SMALL SIGNAL TRANSISTOR IN SOT23

#### **Features**

- Ideally Suited for Automatic Insertion
- Complementary NPN Types: BC846 BC848
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

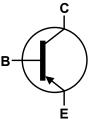
### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <a>®3</a>
- Weight: 0.008 grams (Approximate)

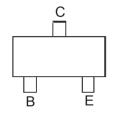




Top View



Device Symbol



Top View Pin-Out

### Ordering Information (Note 4)

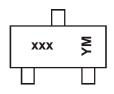
Product	Compliance	Marking	Reel Size (Inches)	Quantity per Reel
BC856A-7-F	Standard	K3A	7	3,000
BC856B-7-F	Standard	K3B	7	3,000
BC856B-13-F	Standard	K3B	13	10,000
BC857A-7-F	Standard	K3A	7	3,000
BC857B-7-F	Standard	K3B	7	3,000
BC857B-13-F	Standard	K3B	13	10,000
BC857C-7-F	Standard	K3G	7	3,000
BC857C-13-F	Standard	K3G	13	10,000
BC858A-7-F	Standard	K3A	7	3,000
BC858B-7-F	Standard	K3B	7	3,000
BC858C-7-F	Standard	K3G	7	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



### **Marking Information**



 $\begin{array}{lll} xxx = & Product Type Marking Code \\ & (Please see Ordering Information) \\ YM = & Date Code Marking \\ Y or \overline{Y} = & Year (ex: G = 2019) \\ M or \overline{M} = & Month (ex: 9 = September) \\ \end{array}$ 

Date Code Key

Year	2019		2020	2021		2022	2023		2024	2025		2026
Code	G		Н			J	K		L	M		N
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

## Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteris	tic	Symbol	Value	Unit
	BC856		-80	
Collector-Base Voltage	BC857	V <sub>CBO</sub>	-50	V
	BC858		-30	
	BC856		-65	
Collector-Emitter Voltage	BC857	V <sub>CEO</sub>	-45	V
	BC858		-30	
Emitter-Base Voltage		V <sub>EBO</sub>	-5.0	V
Continuous Collector Current		Ic	-100	mA
Peak Collector Current (Single Pulse)		I <sub>CM</sub>	-200	mA
Peak Emitter Current		I <sub>EM</sub>	-200	mA
Peak Base Current (Single Pulse)		I <sub>BM</sub>	-200	mA

# Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	ס	310	mW	
Power Dissipation	(Note 6)	$P_{D}$	350	IIIVV	
Thermal Resistance, Junction to Ambient	(Note 5)	J	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ heta JA}$	357	C/VV	
Thermal Resistance, Junction to Leads (Note 7)		$R_{ heta JL}$	350	°C/W	
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C		

### ESD Ratings (Note 8)

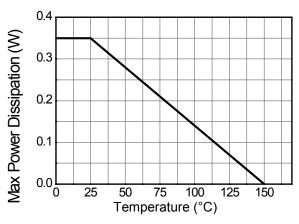
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

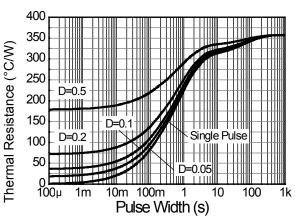
Notes: 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

- 6. Same as Note 5, except the device is mounted on 15mm  $\times$  15mm 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the leads).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



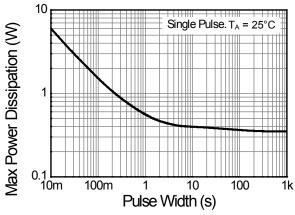
# **Thermal Characteristics and Derating Information**





# **Derating Curve**

**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



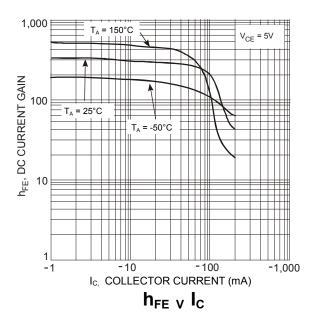
# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

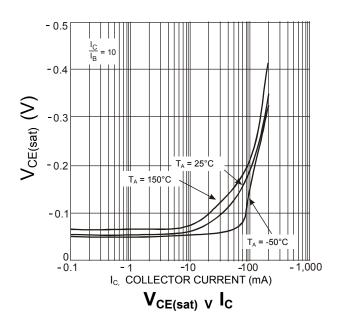
Ch	aracteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
		BC856	-	-80					
Collector-Base Breakdown Voltage		BC857	BV <sub>CBO</sub>	-50	Ī —	_	V	I <sub>C</sub> = -10μA	
		BC858		-30					
0    1    5    1    5    1		BC856		-65					
Collector-Emitter Breakdow (Note 9)	n Voltage	BC857	BV <sub>CEO</sub>	-45	_	_	V	I <sub>C</sub> = -10mA	
(Note 9)		BC858	1	-30					
Emitter-Base Breakdown Vo	oltage		BV <sub>EBO</sub>	-5	_	_	٧	$I_E = -1\mu A$	
Collector Cutoff Current			I <sub>CBO</sub>	_	_	-15	nA	V <sub>CB</sub> = -30V	
Concotor Cuton Current			ICBO			-4	μΑ	$V_{CB} = -30V, T_J = +150^{\circ}C$	
		BC856				-15		V <sub>CE</sub> = -80V	
Collector Emitter Cutoff Cur	rent	BC857	ICES	_	_	-15	nA	V <sub>CE</sub> = -50V	
		BC858				-15		V <sub>CE</sub> = -30V	
Emitter-Base Cutoff Current	t		I <sub>EBO</sub>		_	-100	nA	V <sub>EB</sub> = -5V	
	BC856A / B	C857A / BC858A			200				
Small Signal Current Gain	BC856B / B	C857B / BC858B	h <sub>fe</sub>	_	330	_	_		
	BC857	'C / BC858C			600				
	BC856A / BC857A / BC858A BC856B / BC857B / BC858B		h <sub>ie</sub>	_	2.7	_	kΩ	I <sub>C</sub> = -2.0mA, V <sub>CE</sub> = -5V f = 1.0kHz	
Input Impedance					4.5				
	BC857C / BC858C				8.7				
Output Admittance	BC856A / BC857A / BC858A		h <sub>oe</sub>	_	18		μS		
Output Admittance	BC856B / BC857B / BC858B				30	_			
	BC857	C / BC858C			60				
Reverse Voltage Transfer	BC856A / BC857A / BC858A			_	1.5x10 <sup>-4</sup>		_		
Ratio	BC856B / BC857B / BC858B		h <sub>re</sub>		2x10 <sup>-4</sup>	_			
		C / BC858C			3x10 <sup>-4</sup>				
	BC856A / BC857A / BC858A			125	180	250			
DC Current Gain (Note 9)		C857B / BC858B	h <sub>FE</sub>	220	290	475	_	$I_C = -2.0 \text{mA}, V_{CE} = -5 \text{V}$	
	BC857	'C / BC858C		420	520	800			
Collector-Emitter Saturation	Voltage (Note 9	9)	V <sub>CE(sat)</sub>	_	-75	-300	mV	$I_C = -10mA$ , $I_B = -0.5mA$	
		,	02(00.)		-250	-650		$I_C = -100 \text{mA}, I_B = -5.0 \text{mA}$	
Base-Emitter Turn-On Volta	ige (Note 9)		V <sub>BE(on)</sub>	-600	-650	-750	mV	$I_C = -2mA, V_{CE} = -5V$	
			* BE(OII)	_		-820		$I_C = -10 \text{mA}, V_{CE} = -5 \text{V}$	
Base-Emitter Saturation Vo	Itage (Note 9)		V <sub>BE(sat)</sub>	_	-700	_	mV	$I_C = -10mA$ , $I_B = -0.5mA$	
			V DL(Sat)		-850	-1100		$I_C = -100 \text{mA}, I_B = -5 \text{mA}$	
Output Capacitance			C <sub>obo</sub>		3	_	pF	$V_{CB} = -10V, f = 1.0MHz$	
Transition Frequency			f <sub>T</sub>	100	200	_	MHz	$V_{CE} = -5V, I_{C} = -10mA,$ f = 100MHz	
Noise Figure			NF	_	2	10	dB	$V_{CE}$ = -5V, $I_{C}$ = -200 $\mu$ A $R_{S}$ = 2k $\Omega$ , $f$ = 1kHz $\Delta f$ = 200Hz	

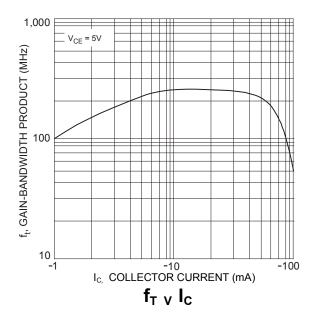
Note: 9. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s$ . Duty cycle  $\leq 2\%$ .



## Typical Electrical Characteristics (BC856B) (@ T<sub>A</sub> = +25°C, unless otherwise specified.)





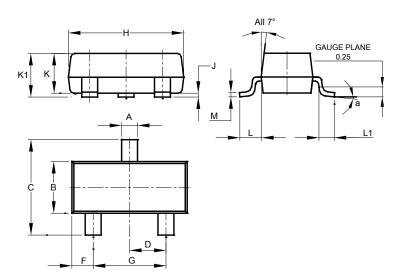




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

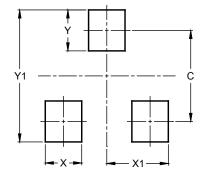


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
C	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
H	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	All Dimensions in mm						

# **Suggested Pad Layout**

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html \ for the \ latest \ version.$ 

#### SOT23



Dimensions	Value (in mm)
C	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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